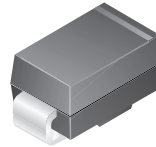


ES1A - ES1D

Features

- For surface mount applications.
- Glass passivated junction.
- Low profile package.
- Easy pick and place.
- Built-in strain relief.
- Superfast recovery times for high efficiency.


SMA/DO-214AC

COLOR BAND DENOTES CATHODE

1.0 Ampere Superfast Rectifiers

Absolute Maximum Ratings*

 $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$I_{F(AV)}$	Average Rectified Current @ $T_A = 120^\circ\text{C}$	1.0	A
I_{FSM}	Non-repetitive Peak Forward Surge Current 8.3 ms single half-sine-wave Superimposed on rated load (JEDEC method)	30	A
P_D	Total Device Dissipation Derate above 25°C	1.47 11.76	W mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient**	85	$^\circ\text{C/W}$
$R_{\theta JL}$	Thermal Resistance, Junction to Lead**	35	$^\circ\text{C/W}$
T_{stg}	Storage Temperature Range	-50 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	-50 to +150	$^\circ\text{C}$

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

**Device mounted on FR-4 PCB 0.013 mm.

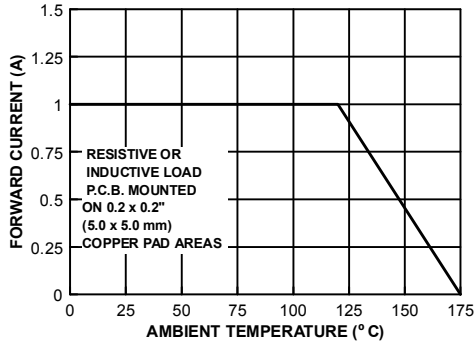
Electrical Characteristics

 $T_A = 25^\circ\text{C}$ unless otherwise noted

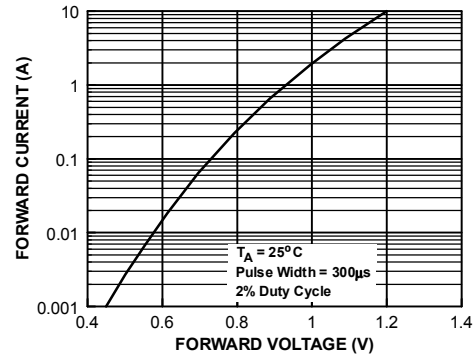
Symbol	Parameter	Device				Units
		1A	1B	1C	1D	
V_{RRM}	Maximum Repetitive Reverse Voltage	50	100	150	200	V
V_{RMS}	Maximum RMS Voltage	35	70	105	140	V
V_R	DC Reverse Voltage (Rated V_R)	50	100	150	200	V
I_{RM}	Maximum Instantaneous Reverse Current @ rated V_R $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	5.0 100				μA μA
t_{rr}	Maximum Reverse Recovery Time $I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{RR} = 0.25\text{ A}$	15				ns
V_{FM}	Maximum Instantaneous Forward Voltage @ 1.0 A	0.92				V
C	Typical Junction Capacitance $V_R = 4.0\text{ V}$, $f = 1.0\text{ MHz}$	7.0				pF

Typical Characteristics

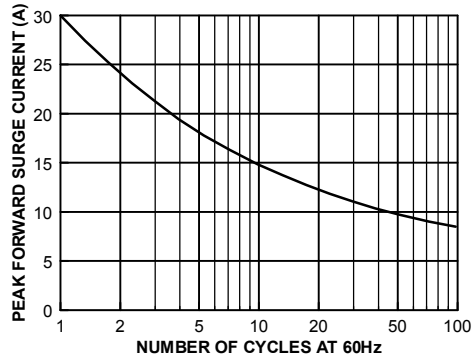
Forward Current Derating Curve



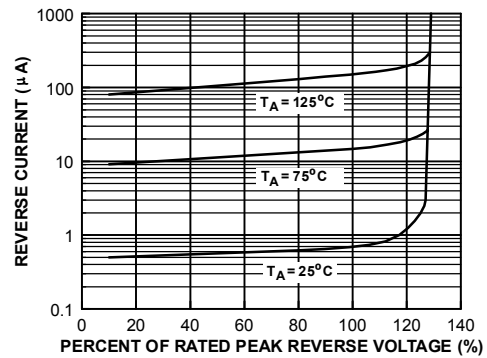
Forward Characteristics



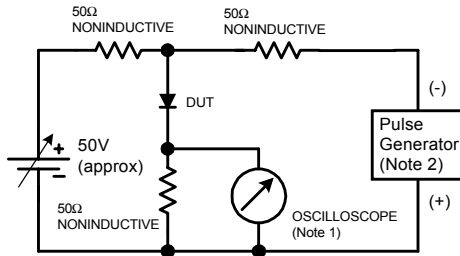
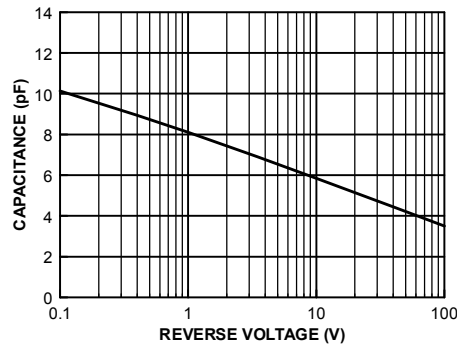
Non-Repetitive Surge Current



Reverse Characteristics

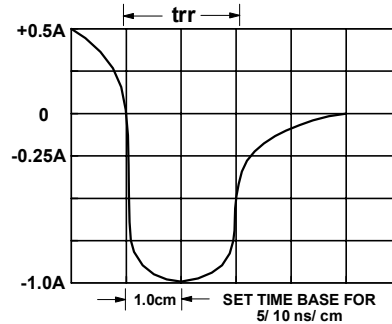


Junction Capacitance



NOTES:

1. Rise time = 7.0 ns max; Input impedance = 1.0 megaohm 22 pf.
2. Rise time = 10 ns max; Source impedance = 50 ohms.

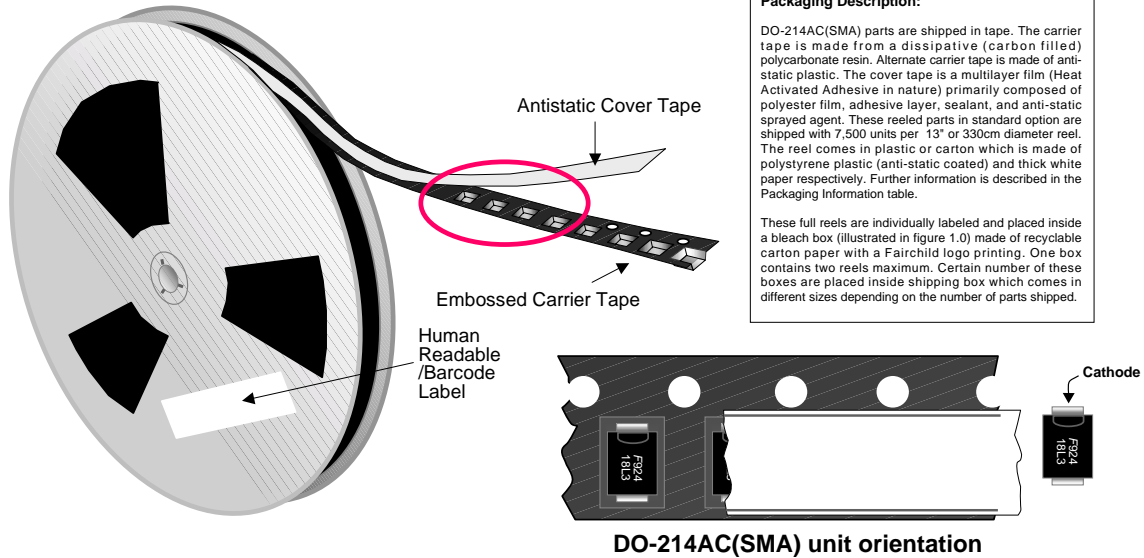


Reverse Recovery Time Characteristic and Test Circuit Diagram

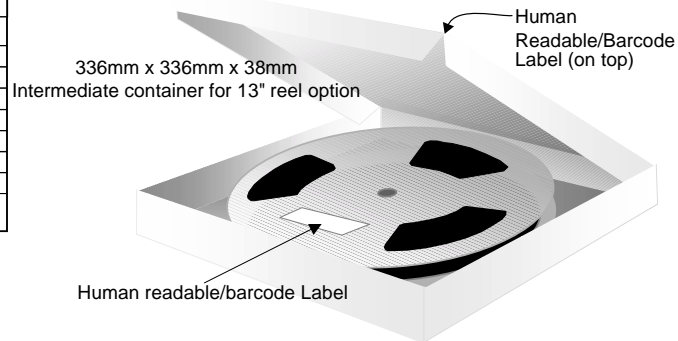
DO-214AC(SMA) Tape and Reel Data

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DO-214AC(SMA) Packaging Configuration: Figure 1.0



DO-214AC(SMA) Packaging Information		
Packaging Option	Under package code P5	Under package code MA
Packaging type	TNR	TNR
Qty per Reel/Tube/Bag	7,500	5,000
Reel Size (inch diameter)	13	13
Box Dimension (mm)	336X336X38	340X350X340
Max qty per Box	15,000	10,000
Weight per unit (gm)	0.064	0.064
Weight per Reel (kg)	0.860	0.750
Note/Comments	Human readable label	Barcode label



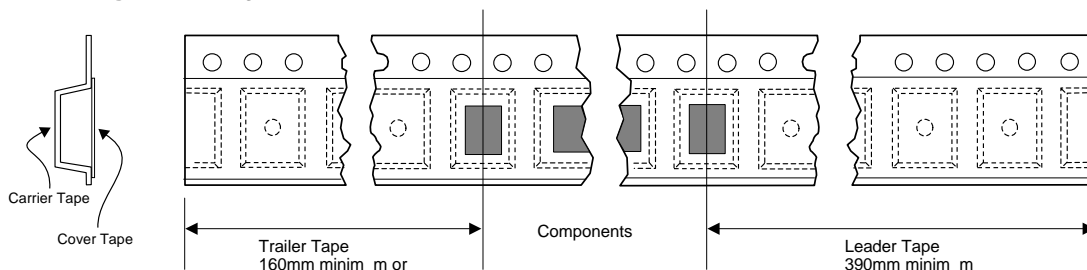
Human Readable Label sample



F63TNR Label sample



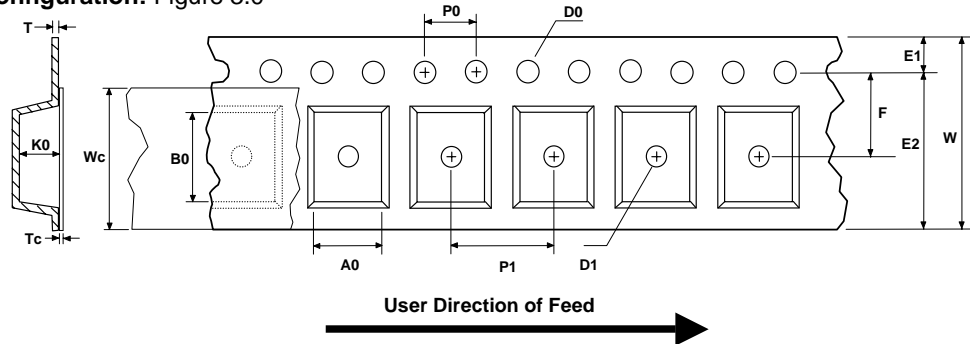
DO-214AC(SMA) Tape Leader and Trailer Configuration: Figure 2.0



DO-214AC(SMA) Tape and Reel Data, continued

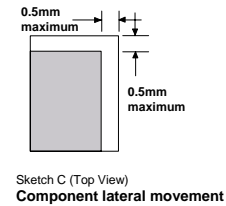
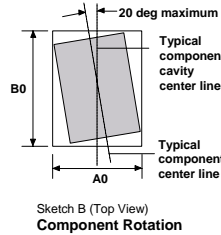
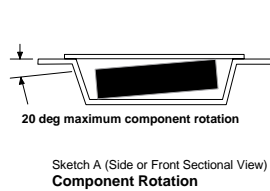
DO-214AC(SMA) Embossed Carrier Tape

Configuration: Figure 3.0



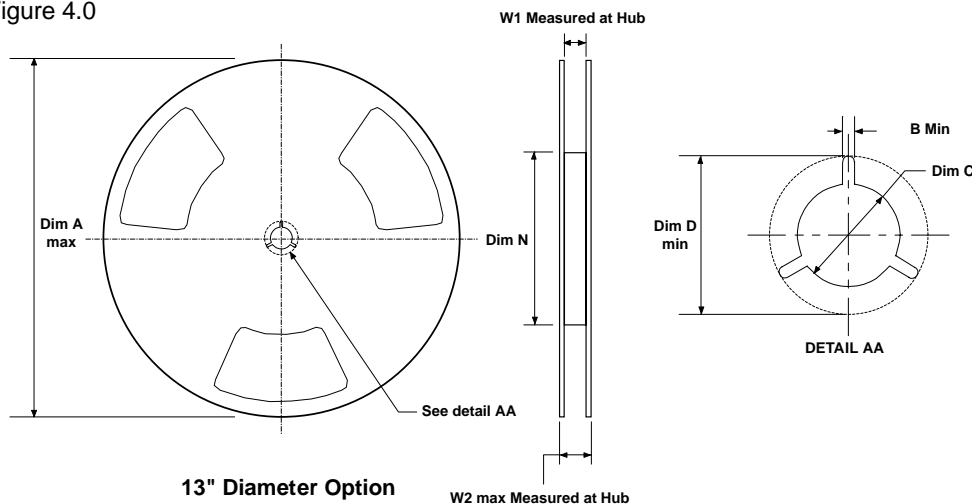
Dimensions are in millimeter														
Pkg type	A0	B0	W	D0	D1	E1	E2	F	P1	P0	K0	T	Wc	Tc
DO-214AC(SMA) (12mm)	2.72 ±0.10	5.25 ±0.10	12.0 ±0.3	1.55 ±0.05	1.125 ±0.125	1.75 ±0.10	10.25 min	5.5 ±0.05	4.0 ±0.1	4.0 ±0.1	2.45 ±0.10	0.23 ±0.10	9.3 ±0.025	0.06 ±0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



DO-214AC(SMA) Reel Configuration:

Figure 4.0

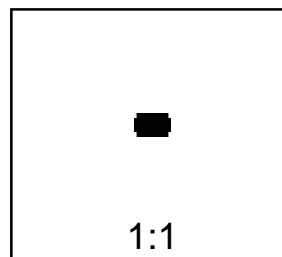
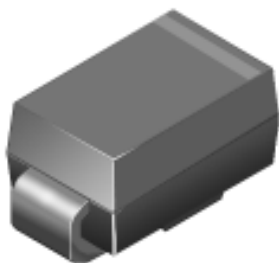


Dimensions are in inches and millimeters								
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2
12mm	13" Dia	13.0 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	1.97 50 min	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4

DO-214AC(SMA) Package Dimensions



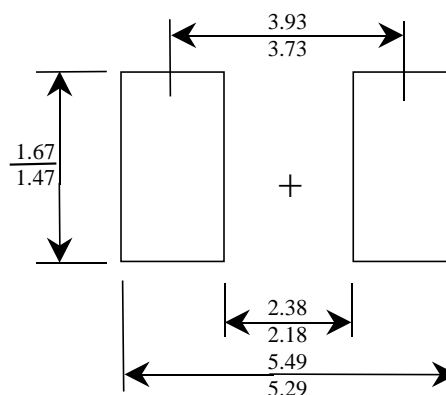
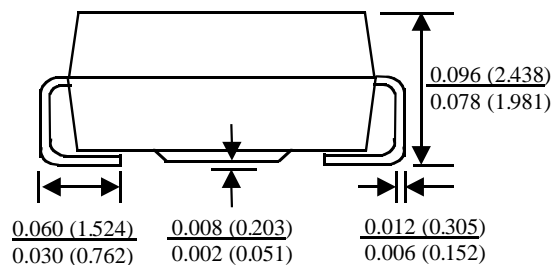
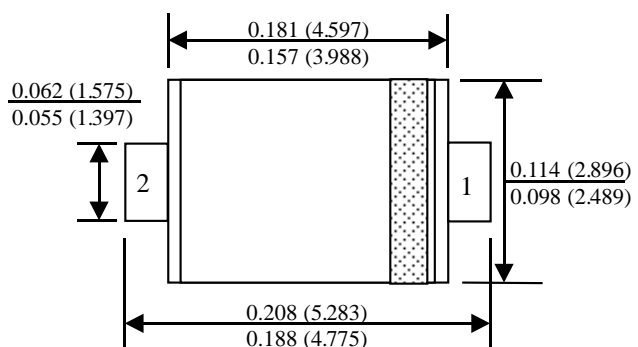
DO-214AC(SMA) (FS PKG Code P5)



Scale 1:1 on letter size paper

Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.064



Minimum Recommended
Land Pattern

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DOME™	ISOPLANAR™	Quiet Series™	
E ² CMOS™	MICROWIRE™	SILENT SWITCHER®	
EnSigna™	OPTOLOGIC™	SMART START™	
FACT™	OPTOPLANAR™	SuperSOT™-3	
FACT Quiet Series™	PACMAN™	SuperSOT™-6	
FAST®	POP™	SuperSOT™-8	

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